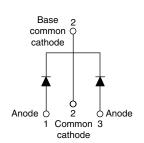


Vishay Semiconductors

# Schottky Rectifier, 2 x 15 A

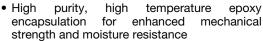




PRODUCT SUMMARY				
Package	TO-220AB			
I <sub>F(AV)</sub>	2 x 15 A			
$V_R$	45 V			
V <sub>F</sub> at I <sub>F</sub>	See Electrical table			
I <sub>RM</sub> max.	100 mA at 125 °C			
T <sub>J</sub> max.	150 °C			
Diode variation	Common cathode			
E <sub>AS</sub>	10 mJ			

#### **FEATURES**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

#### **DESCRIPTION**

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES UN		
I <sub>F(AV)</sub>	Rectangular waveform (per device)	30	Α	
V <sub>RRM</sub>		35/45	V	
I <sub>FRM</sub>	T <sub>C</sub> = 123 °C (per leg)	30	۸	
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1020	- A	
V <sub>F</sub>	20 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.6	V	
T <sub>J</sub>	Range	- 65 to 150	°C	

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-MBR3045CTPbF	VS-MBR3045CT-N3	UNITS	
Maximum DC reverse voltage	$V_{R}$	45	45	V	
Maximum working peak reverse voltage	$V_{RWM}$	40	40	V	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average per leg		T <sub>C</sub> = 123 °C, rated V <sub>R</sub>		15 30	
forward current per device	I <sub>F(AV)</sub>				
Peak repetitive forward current per leg	I <sub>FRM</sub>	Rated V <sub>R</sub> , square wave, 20 kHz, T <sub>C</sub> = 123 °C		30	
Non-repetitive peak surge current	I <sub>FSM</sub>	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	1020	Α
	1 0.00	Surge applied at rated load single phase, 60 Hz	conditions halfwave,	200	
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	$T_J = 25  ^{\circ}\text{C},  I_{AS} = 2  \text{A},  L = 5  \text{mH}$		10	mJ
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		Α	



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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	30 A	T <sub>J</sub> = 25 °C	0.76	V
		20 A	T <sub>J</sub> = 125 °C	0.6	
		30 A		0.72	
Maximum instantaneous reverse current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	Rated DC voltage	1	A
		T <sub>J</sub> = 125 °C		100	mA
Threshold voltage	V <sub>F(TO)</sub>	T <sub>J</sub> = T <sub>J</sub> maximum		0.29	V
Forward slope resistance	r <sub>t</sub>			13.6	mΩ
Maximum junction capacitance	C <sub>T</sub>	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		800	pF
Typical series inductance	L <sub>S</sub>	Measured from top of terminal to mounting plane 8.0 nl		nΗ	
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub> 10 000 V/μs		V/µs	

#### Note

 $<sup>^{(1)}</sup>$  Pulse width < 300  $\mu$ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature range	$T_J$		- 65 to 150	°C	
Maximum storage temperature range	T <sub>Stg</sub>		- 65 to 175	٠.	
Maximum thermal resistance, junction to case per leg	R <sub>thJC</sub>	DC operation	1.5		
Typical thermal resistance, case to heatsink	R <sub>thCS</sub> Mounting surface, smooth and greased Only for TO-220		0.50	°C/W	
Maximum thermal resistance, junction to ambient	R <sub>thJA</sub>	R <sub>thJA</sub> DC operation 50 For D <sup>2</sup> PAK and TO-262			
Approximate weight			2	g	
Approximate weight			0.07	OZ.	
Mounting torque minimum		Non-lubricated threads	6 (5)	kgf ⋅ cm	
Mounting torque maximum		Non-iublicateu tilleaus	12 (10)	$(lbf \cdot in)$	
Marking device		Case style TO-220AB MBR3045CT		045CT	

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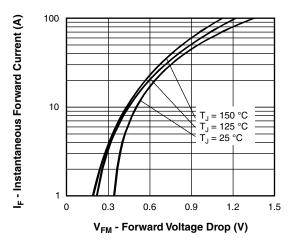


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

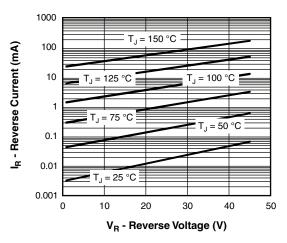


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

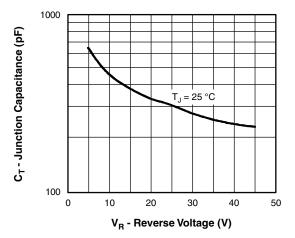


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

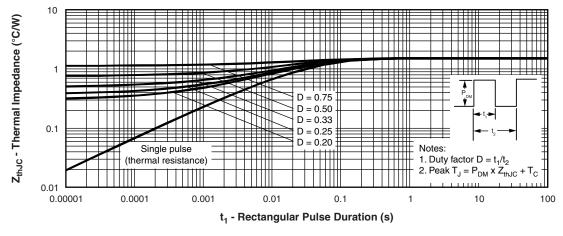


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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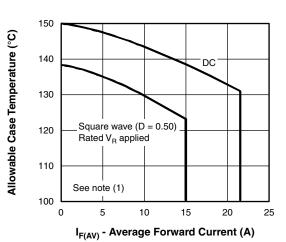


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

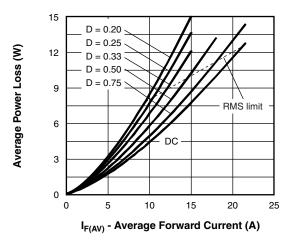


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

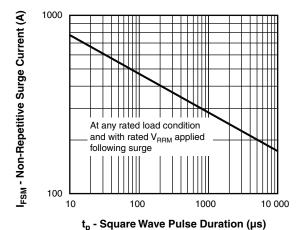


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

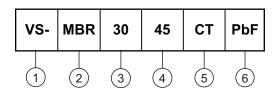
#### Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$ 

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#### **ORDERING INFORMATION TABLE**

**Device code** 



Vishay Semiconductors product

2 - Schottky MBR series

3 - Current rating (30 = 30 A)

- Voltage ratings (045 = 45 V)

- CT = Essential part number

6 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)				
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION	
VS-MBR3045CTPbF	50	1000	Antistatic plastic tube	
VS-MBR3045CT-N3	50	1000	Antistatic plastic tube	

LINKS TO RELATED DOCUMENTS				
Dimensions		www.vishay.com/doc?95222		
Dort moulcing information	TO-220AB PbF	www.vishay.com/doc?95225		
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028		



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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.

Revision: 02-Oct-12 Document Number: 91000